Supplementary Materials

Using Thermally Crosslinkable Hole Transporting Layer to Improve Interface Characteristics for Perovskite CsPbBr3 Quantum-Dot Light-Emitting Diodes

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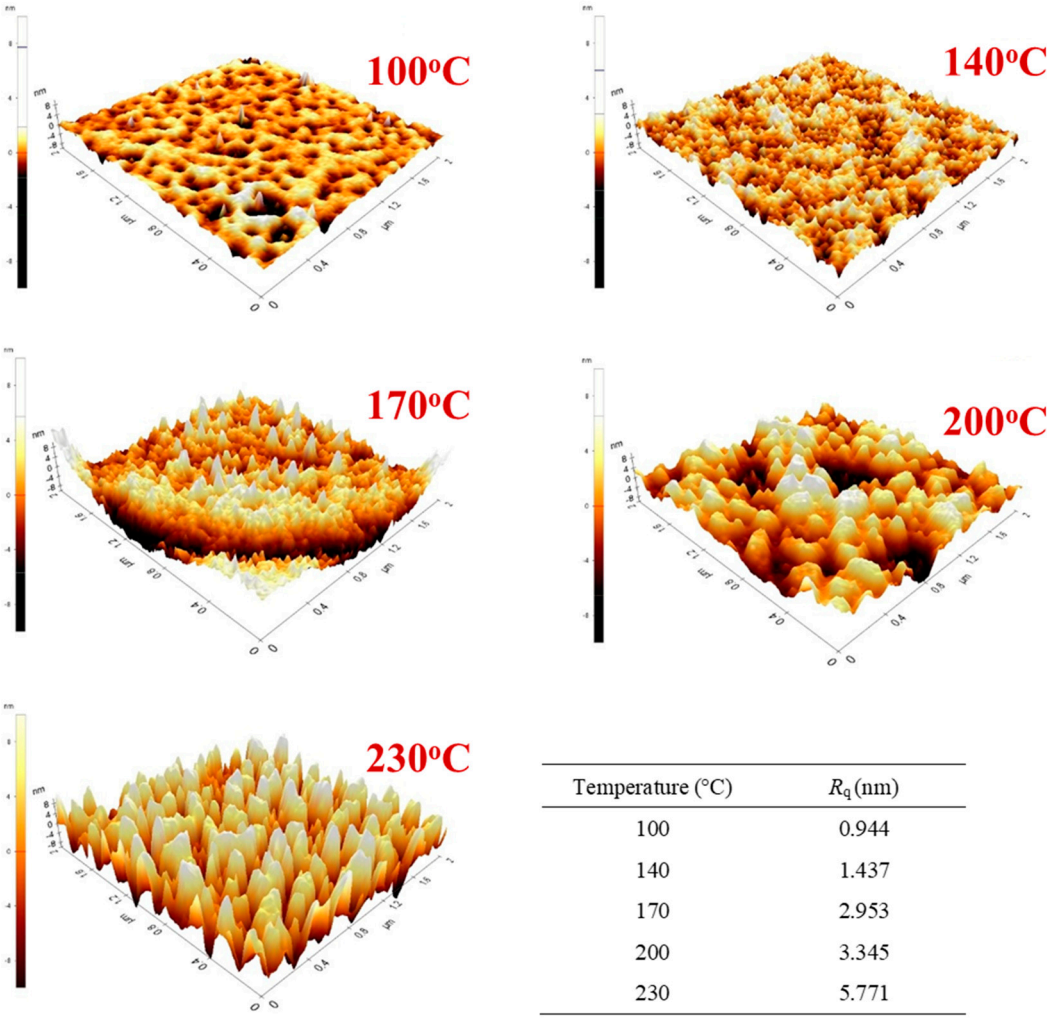

Temperature (°C)	R_q (nm)
100	0.944
140	1.437
170	2.953
200	3.345
230	5.771

Figure S1. Surface AFM images of VB-FNPD films crosslinking at different temperature.

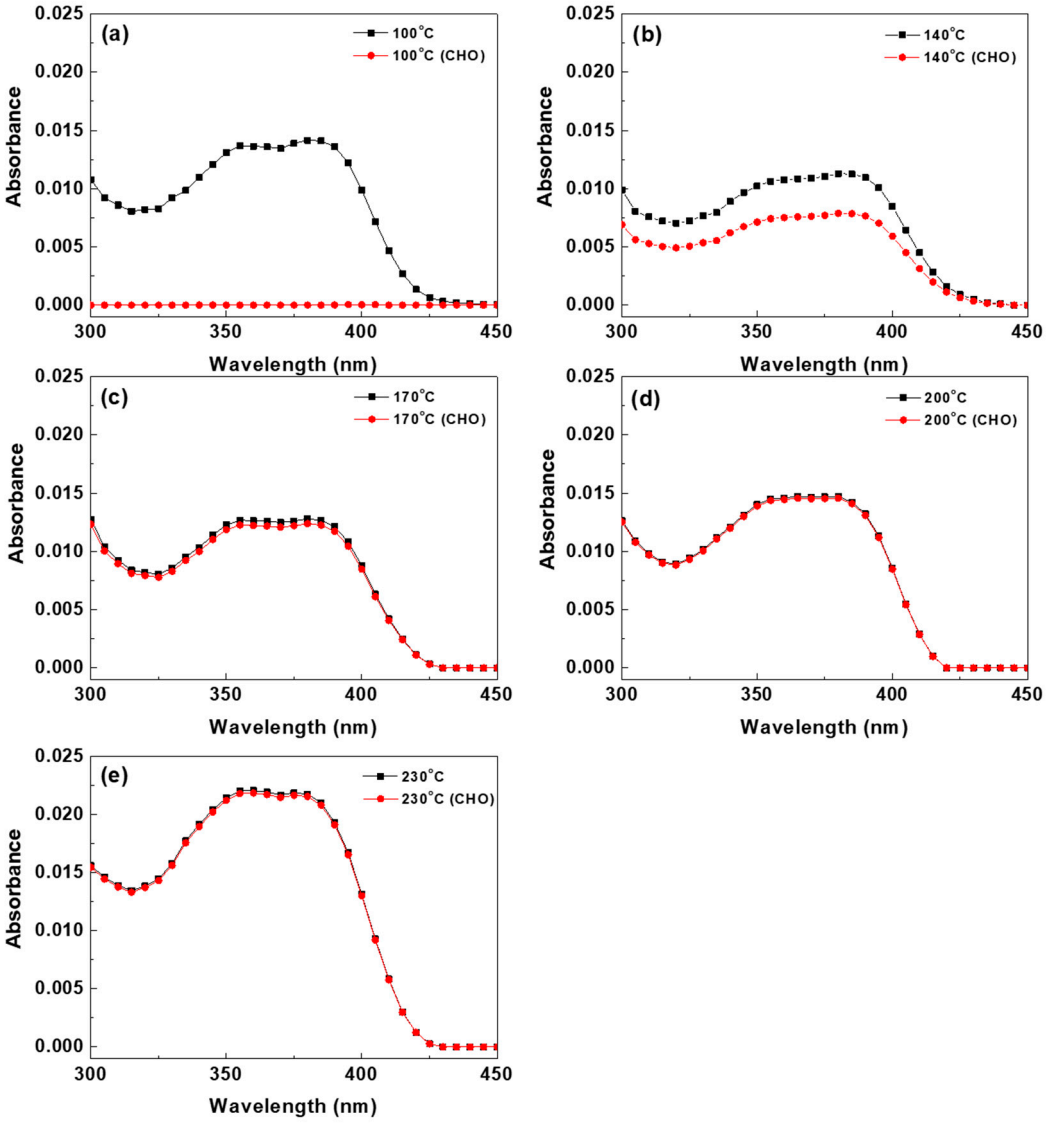

Figure S2. Comparison of absorbance for VB-FNPD films crosslinking at different temperature and corresponding samples before and after soaking in CHO.

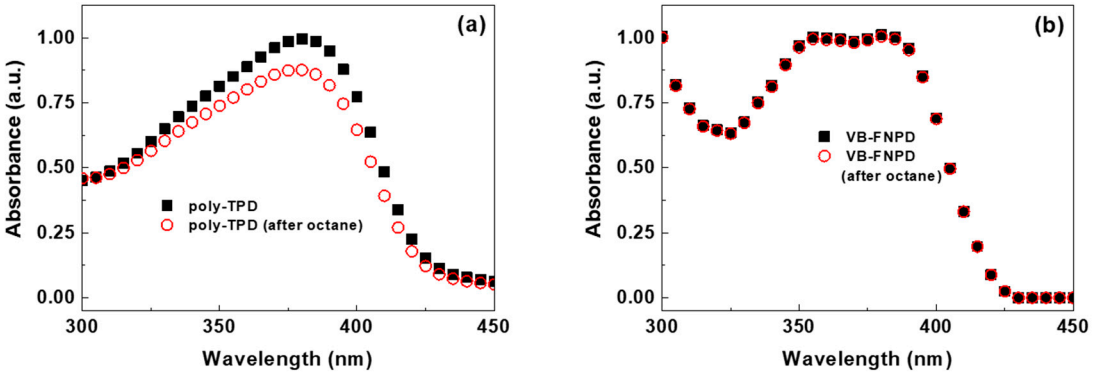

Figure S3. Comparison of washing effect (in octane) of absorbance for (a) poly-TPD and (b) VB-FNPD films.

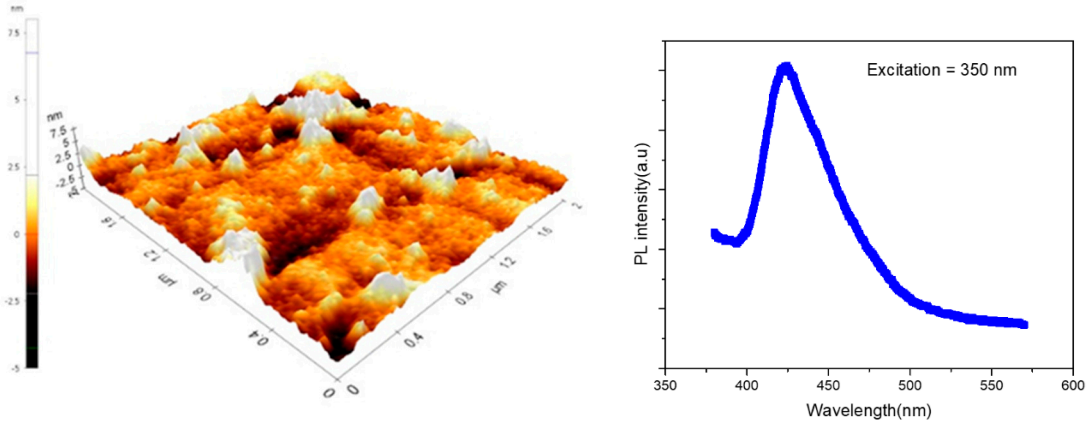

Figure S4. AFM image and PL spectrum of a Poly-TPD film.